NSN 5961-01-245-2057

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View Online at https://aerobasegroup.com/nsn/5961-01-245-2057

Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
1.750 inches
Overall Diameter:
0.370 inches
End Application:
Low altitude navigation & targeting infrared system (lantirn)
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-5
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
3.00 amperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Transfer Ratio:
20.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Weapon system essential; junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead

N/a

Shelf Life:

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Demilitarization:

No

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